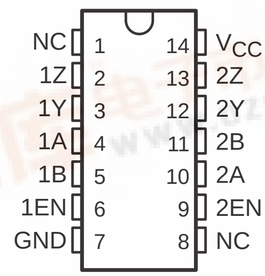
DUAL DIFFERENTIAL LINE DRIVER WITH 3-STATE OUTPUTS

SLLS088B – JANUARY 1977 – REVISED MAY 1995

- **Meets or Exceeds the Requirements of ANSI EIA/TIA-422-B and ITU Recommendation V.11**
- **Single 5-V Supply**
- **Balanced Line Operation**
- **TTL Compatible**
- **High-Impedance Output State for Party-Line Applications**
- **High-Current Active-Pullup Outputs**
- **Short-Circuit Protection**
- **Dual Channels**
- **Clamp Diodes at Inputs**

D OR N PACKAGE
(TOP VIEW)



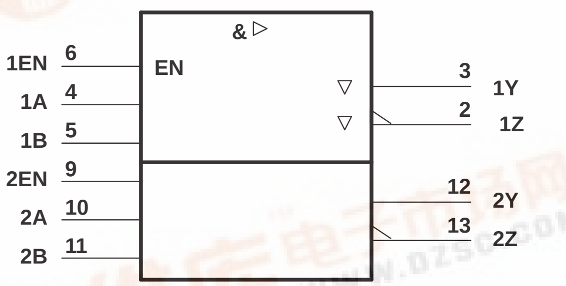
NC – No internal connection

description

The SN75159 dual differential line driver with 3-state outputs is designed to provide all the features of the SN75158 line driver with the added feature of driver output controls. There is an individual control for each driver. When the output control is low, the associated outputs are in a high-impedance state and the outputs can neither drive nor load the bus. This permits many devices to be connected together on the same transmission line for party-line applications.

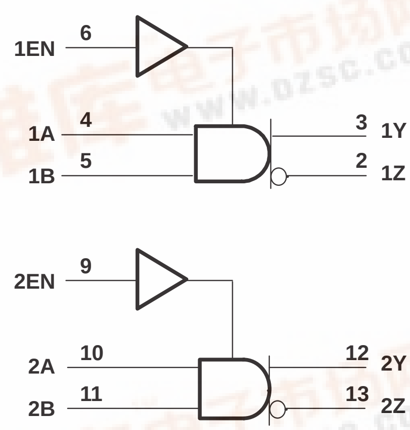
The SN75159 is characterized for operation from 0°C to 70°C.

logic symbol†

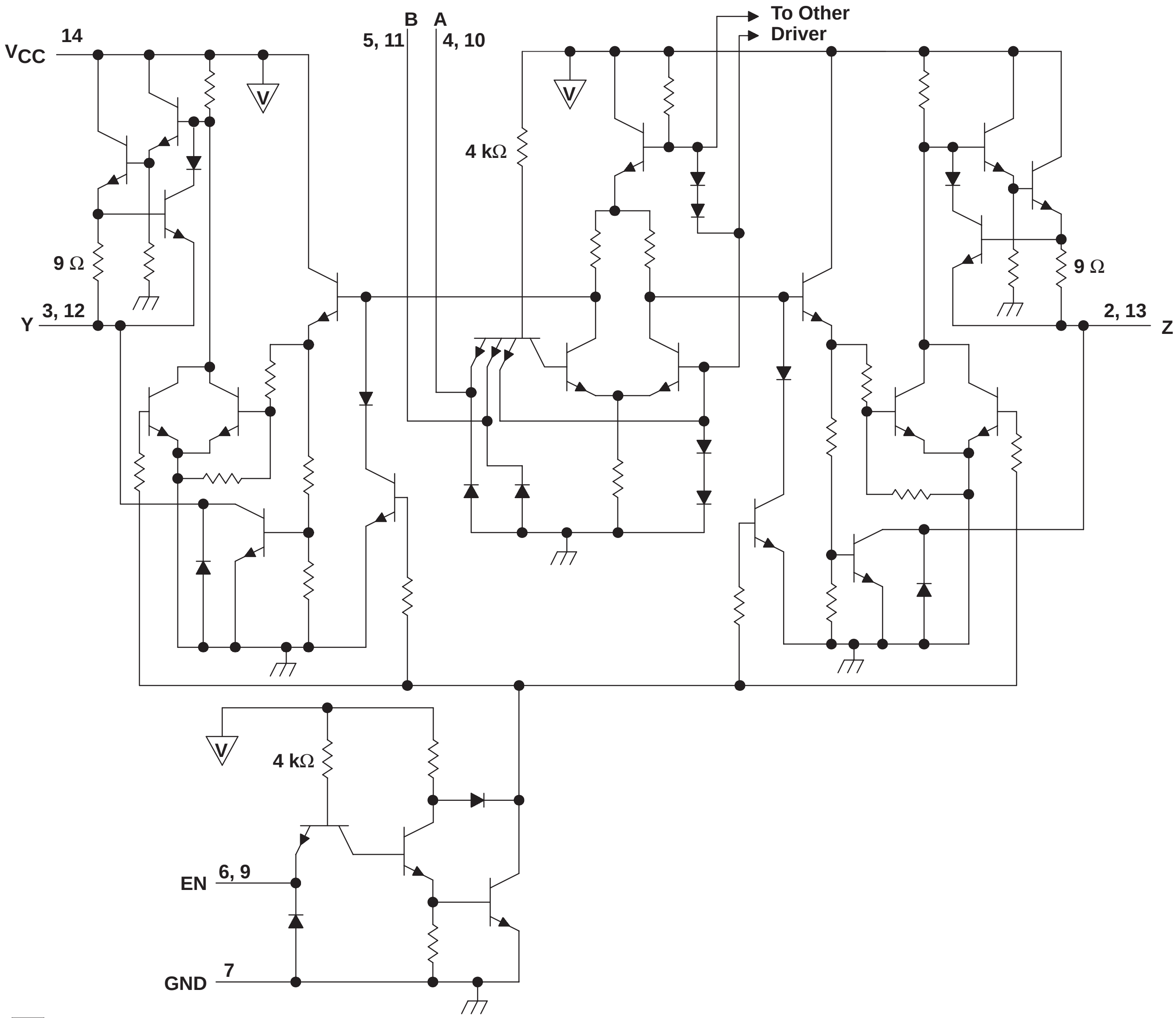


† This symbol is in accordance with ANSI/IEEE Std 91-1984 and IEC Publication 617-12.

logic diagram (positive logic)



schematic (each driver)



V . . . V_{CC} bus

Resistor values shown are nominal.

absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V_{CC} (see Note 1) . . . . 7 V
Input voltage, V_I . . . . 5.5 V
Off-state voltage applied to open-collector outputs . . . . 12 V
Continuous total dissipation . . . . See Dissipation Rating Table
Operating free-air temperature range, T_A . . . . 0°C to 70°C
Storage temperature range, T_{stg} . . . . –65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds . . . . 260°C

† Stresses beyond those listed under “absolute maximum ratings” may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under “recommended operating conditions” is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

NOTE 1: All voltage values except differential output voltage V_{OD} are with respect to the network ground terminal. V_{OD} is at the Y output with respect to the Z output.

DISSIPATION RATING TABLE

PACKAGE	$T_A \le 25°C$ POWER RATING	DERATING FACTOR ABOVE $T_A = 25°C$	$T_A = 70°C$ POWER RATING
D	950 mW	7.6 mW/°C	608 mW
N	1150 mW	9.2 mW/°C	736 mW

recommended operating conditions

	MIN	NOM	MAX	UNIT
Supply voltage, V_{CC}	4.75	5	5.25	V
High-level input voltage, V_{IH}	2			V
Low-level input voltage, V_{IL}			0.8	V
High-level output voltage, I_{OH}			–40	mA
Low-level output current, I_{OL}			40	mA
Operating free-air temperature, T_A	0		70	°C

electrical characteristics over operating free-air temperature range (unless otherwise noted)

PARAMETER		TEST CONDITIONS			MIN	TYP†	MAX	UNIT
V_{IK}	Input clamp voltage	V_{CC} = 4.75 V,	I_I = –12 mA			–0.9	–1.5	V
V_{OH}	High-level output voltage	V_{CC} = 4.75 V, V_{IH} = 2 V,	V_{IL} = 0.8 V, I_{OH} = –40 mA		2.4	3		V
V_{OL}	Low-level output voltage	V_{CC} = 4.75 V, V_{IH} = 2 V,	V_{IL} = 0.8 V, I_{OL} = 40 mA			0.25	0.4	V
V_{OK}	Output clamp voltage	V_{CC} = 5.25 V,	I_O = –40 mA			–1.1	–1.5	V
V_O	Output voltage	V_{CC} = 4.75 V to 5.25 V,	I_O = 0		0		6	V
$\|V_{OD1}\|$	Differential output voltage	V_{CC} = 5.25 V,	I_O = 0			3.5	$2V_{OD2}$	V
$\|V_{OD2}\|$	Differential output voltage	V_{CC} = 4.75 V			2	3		V
$\Delta\|V_{OD}\|$	Change in magnitude of differential output voltage‡	V_{CC} = 4.75 V				±0.02	±0.4	V
V_{OC}	Common-mode output voltage§	V_{CC} = 5.25 V	R_L = 100 Ω, See Figure 1			1.8	3	V
		V_{CC} = 4.75 V				1.5	3	
$\Delta\|V_{OC}\|$	Change in magnitude of common-mode output voltage‡	V_{CC} = 4.75 V to 5.25 V				±0.01	±0.4	V
I_O	Output current with power off	V_{CC} = 0	V_O = 6 V			0.1	100	µA
			V_O = –0.25 V			–0.1	–100	
			V_O = –0.25 V to 6 V				±100	
I_{OZ}	Off-state (high-impedance state) output current	V_{CC} = 5.25 V, Output controls at 0.8 V	T_A = 25°C	V_O = 0 to V_{CC}			±10	µA
			T_A = 70°C	V_O = 0			–20	
				V_O = 0.4 V			±20	
				V_O = 2.4 V			±20	
				V_O = V_{CC}			20	
I_I	Input current at maximum input voltage	V_{CC} = 5.25 V,	V_I = 5.5 V				1	mA
I_{IH}	High-level input current	V_{CC} = 5.25 V,	V_I = 2.4 V				40	µA
I_{IL}	Low-level input current	V_{CC} = 5.25 V,	V_I = 0.4 V			–1	–1.6	mA
I_{OS}	Short-circuit output current¶	V_{CC} = 5.25 V			–40	–90	–150	mA
I_{CC}	Supply current (both drivers)	V_{CC} = 5.25 V, T_A = 25°C,	Inputs grounded, No load			47	65	mA

† All typical values are at V_{CC} = 5 V and T_A = 25°C except for V_{OC}, for which V_{CC} is as stated under test conditions.
‡ $\Delta|V_{OD}|$ and $\Delta|V_{OC}|$ are the changes in magnitudes of V_{OD} and V_{OC}, respectively, that occur when the input is changed from a high level to a low level.
§ In ANSI Standard EIA/TIA-422-B, V_{OC}, which is the average of the two output voltages with respect to GND, is called output offset voltage, V_{OS}.
¶ Only one output should be shorted at a time, and duration of the short circuit should not exceed one second.

switching characteristics over operating free-air temperature range, V_{CC} = 5 V

PARAMETER		TEST CONDITIONS	MIN	TYP†	MAX	UNIT
t_{PLH}	Propagation delay time, low-to-high-level output	C_L = 30 pF, R_L = 100 Ω, See Figure 2, Termination A		16	25	ns
t_{PHL}	Propagation delay time, high-to-low-level output			11	20	ns
t_{PLH}	Propagation delay time, low-to-high-level output	C_L = 15 pF, See Figure 2, Termination B		13	20	ns
t_{PHL}	Propagation delay time, high-to-low-level output			9	15	ns
t_{TLH}	Transition time, low-to-high-level output	C_L = 30 pF, R_L = 100 Ω, See Figure 2, Termination A		4	20	ns
t_{THL}	Transition time, high-to-low-level output			4	20	ns
t_{PZH}	Output enable time to high level	C_L = 30 pF, R_L = 180 Ω, See Figure 3		7	20	ns
t_{PZL}	Output enable time to low level	C_L = 30 pF, R_L = 250 Ω, See Figure 4		14	40	ns
t_{PHZ}	Output disable time from high level	C_L = 30 pF, R_L = 180 Ω, See Figure 3		10	30	ns
t_{PLZ}	Output disable time from low level	C_L = 30 pF, R_L = 250 Ω, See Figure 4		17	35	ns
	Overshoot factor	R_L = 100 Ω, See Figure 2, Termination C			10%	

† All typical values are at T_A = 25°C.

SYMBOL EQUIVALENTS

DATA-SHEET PARAMETER	EIA/TIA-422-B
V_O	V_{oa}, V_{ob}
$\lvert V_{OD1} \rvert$	V_o
$\lvert V_{OD2} \rvert$	V_t
$\Delta \lvert V_{OD} \rvert$	$\lvert \lvert V_t \rvert - \lvert \overline{V}_t \rvert \rvert$
V_{OC}	$\lvert V_{os} \rvert$
$\Delta \lvert V_{OC} \rvert$	$\lvert V_{os} - \overline{V}_{os} \rvert$
I_{OS}	$\lvert I_{sa} \rvert$, $\lvert I_{sb} \rvert$
I_O	$\lvert I_{xa} \rvert$, $\lvert I_{xb} \rvert$

PARAMETER MEASUREMENT INFORMATION

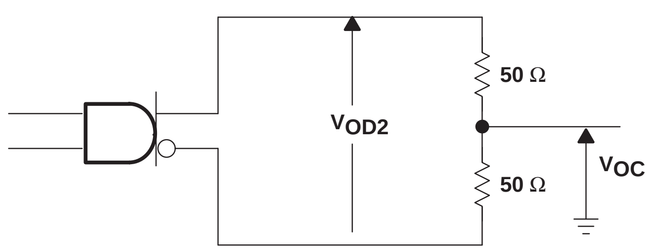
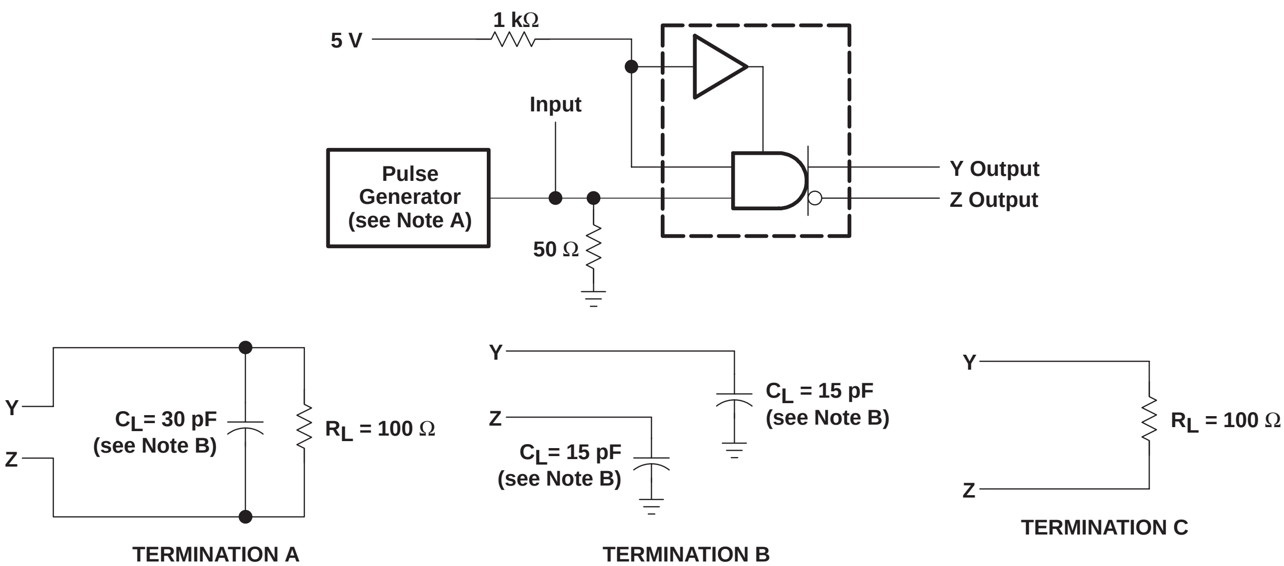
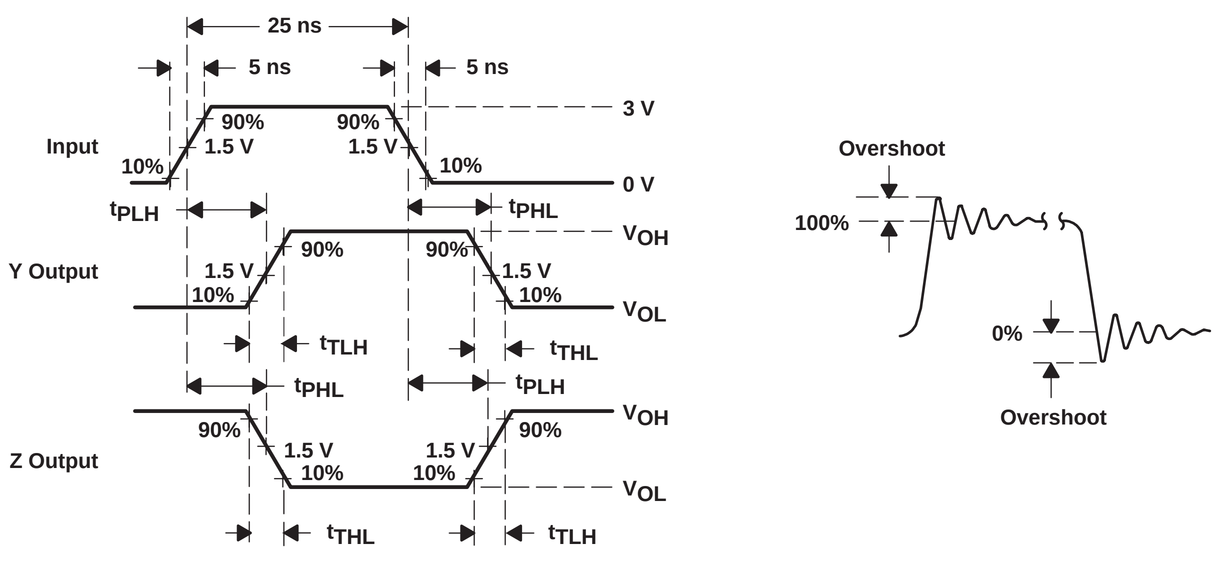


Figure 1. Differential and Common-Mode Output Voltages

PARAMETER MEASUREMENT INFORMATION



TEST CIRCUITS

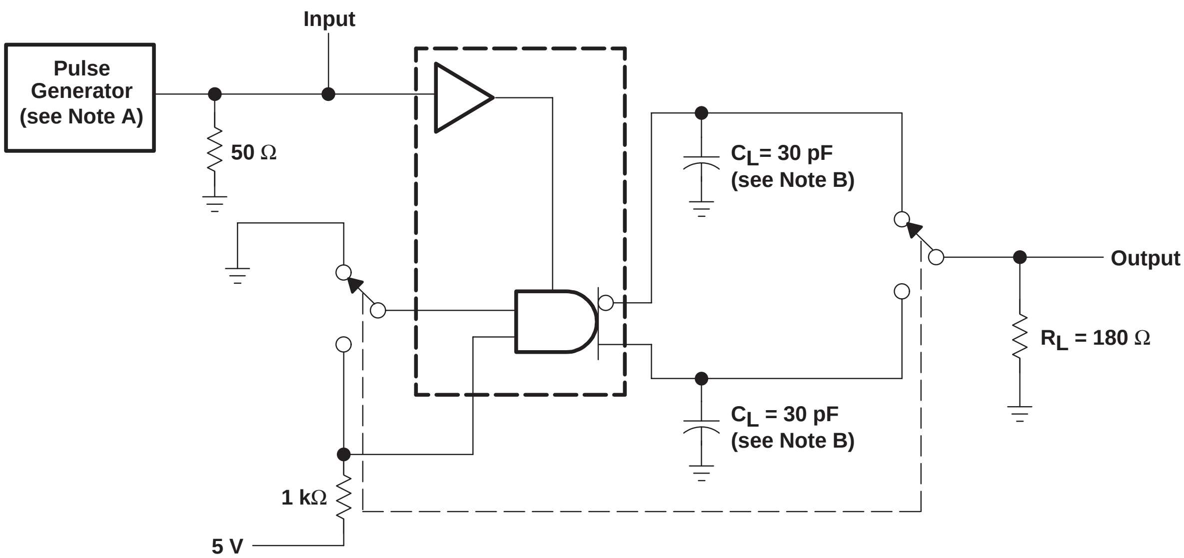


VOLTAGE WAVEFORMS

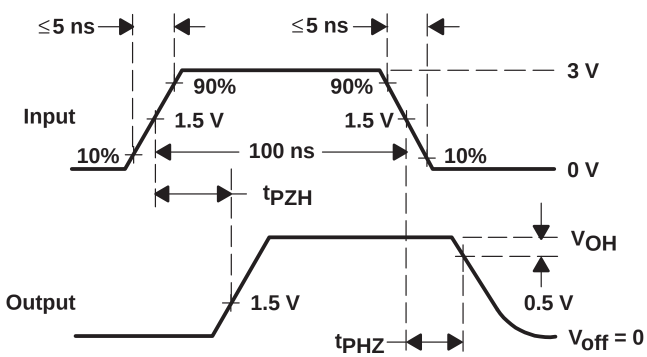
NOTES: A. The pulse generator has the following characteristics: Z_O = 50 Ω, PRR ≤ 10 MHz.
B. C_L includes probe and jig capacitance.

Figure 2. Test Circuits, Voltage Waveforms, and Overshoot Factor

PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT

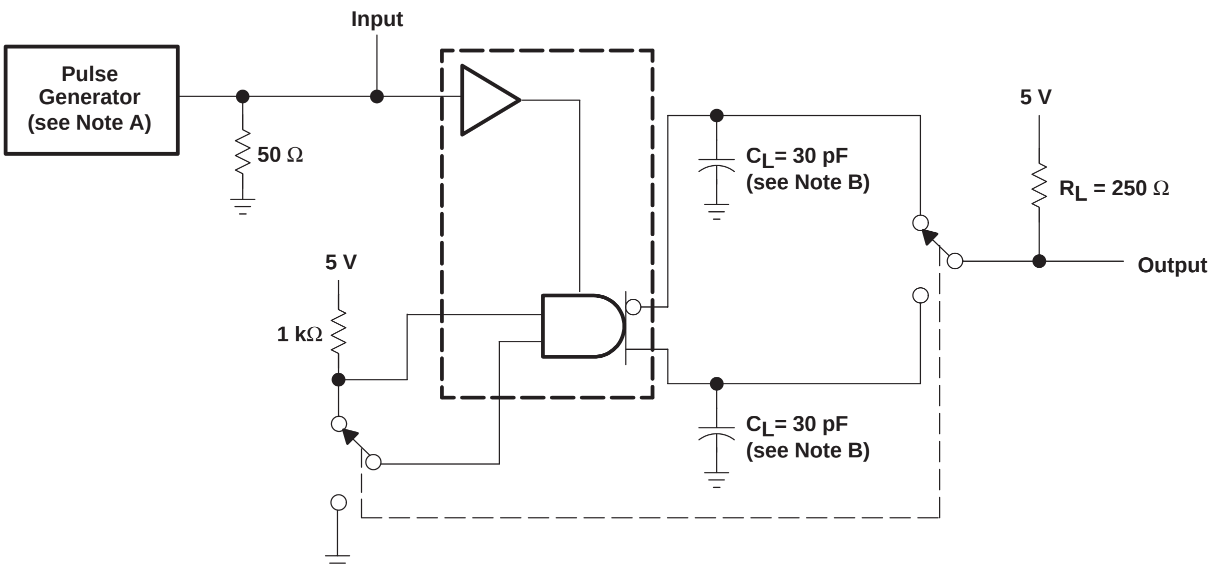


VOLTAGE WAVEFORMS

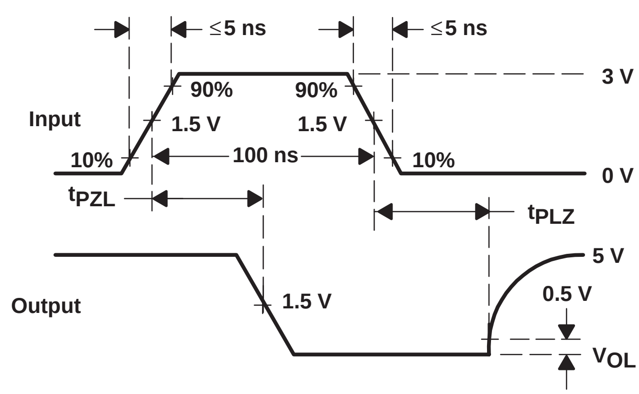
NOTES: A. The pulse generator has the following characteristics: Z_O = 50 Ω, PRR ≤ 500 kHz.
B. C_L includes probe and jig capacitance.

Figure 3. Test Circuit and Voltage Waveforms

PARAMETER MEASUREMENT INFORMATION



TEST CIRCUIT



VOLTAGE WAVEFORMS

NOTES: A. The pulse generator has the following characteristics: Z_O = 50 Ω, PRR ≤ 500 kHz.
B. C_L includes probe and jig capacitance.

Figure 4. Test Circuit and Voltage Waveform

TYPICAL CHARACTERISTICS

OUTPUT VOLTAGE
vs
DATA INPUT VOLTAGE

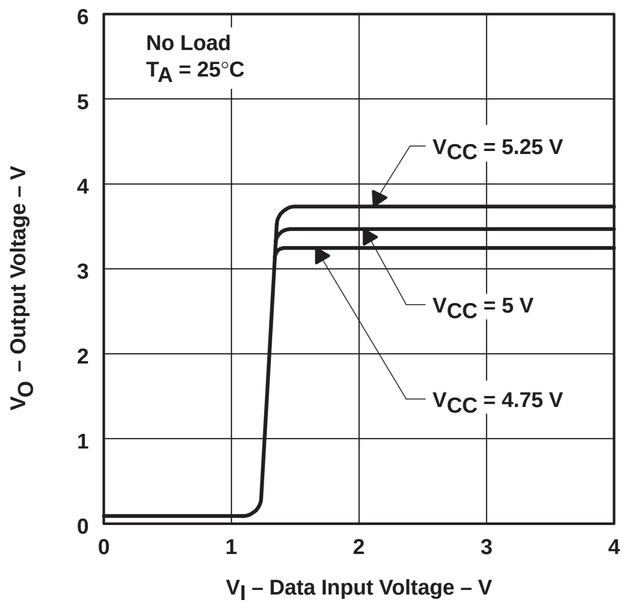


Figure 5

OUTPUT VOLTAGE
vs
DATA INPUT VOLTAGE

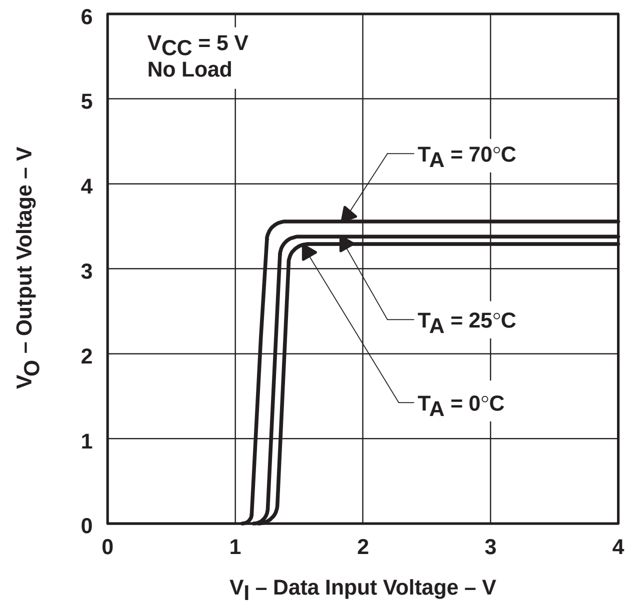


Figure 6

OUTPUT VOLTAGE
vs
FREE-AIR TEMPERATURE

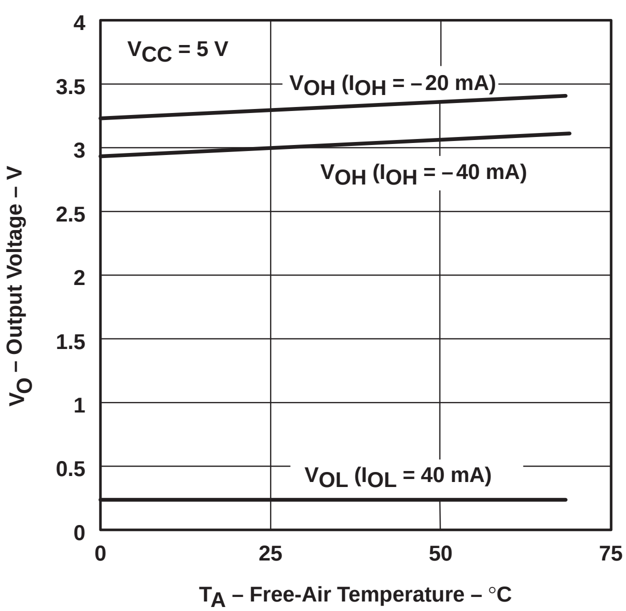


Figure 7

HIGH-LEVEL OUTPUT VOLTAGE
vs
HIGH-LEVEL OUTPUT CURRENT

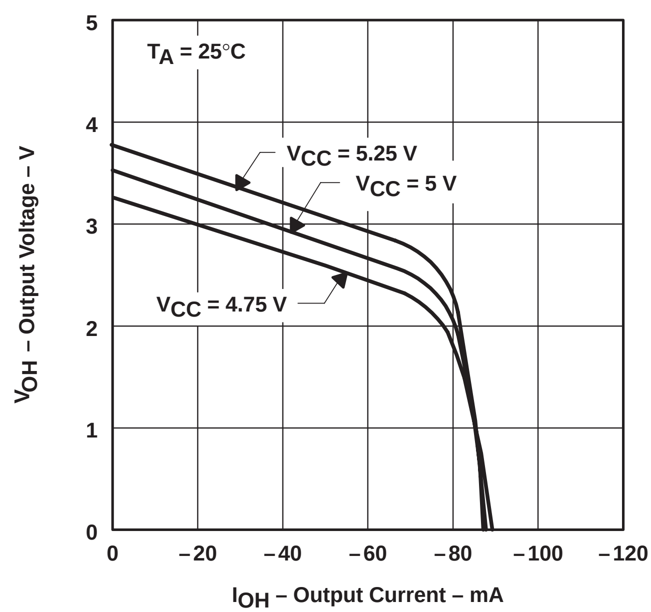


Figure 8

TYPICAL CHARACTERISTICS

LOW-LEVEL OUTPUT VOLTAGE
vs
LOW-LEVEL OUTPUT CURRENT

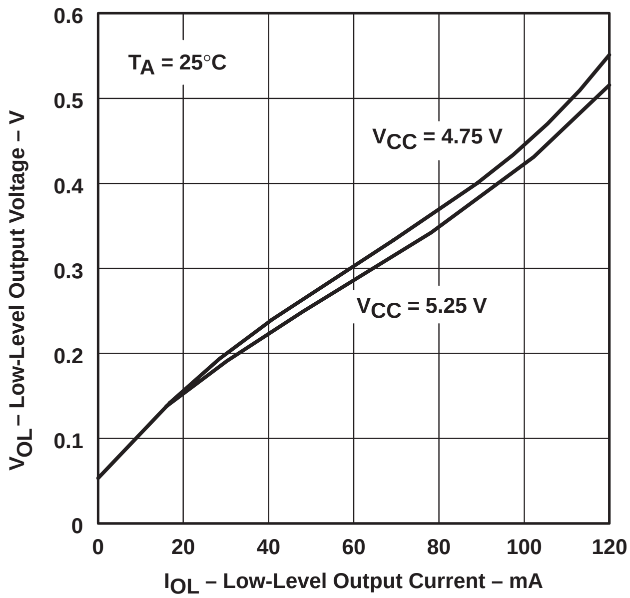


Figure 9

SUPPLY CURRENT
(BOTH DRIVERS)
vs
SUPPLY VOLTAGE

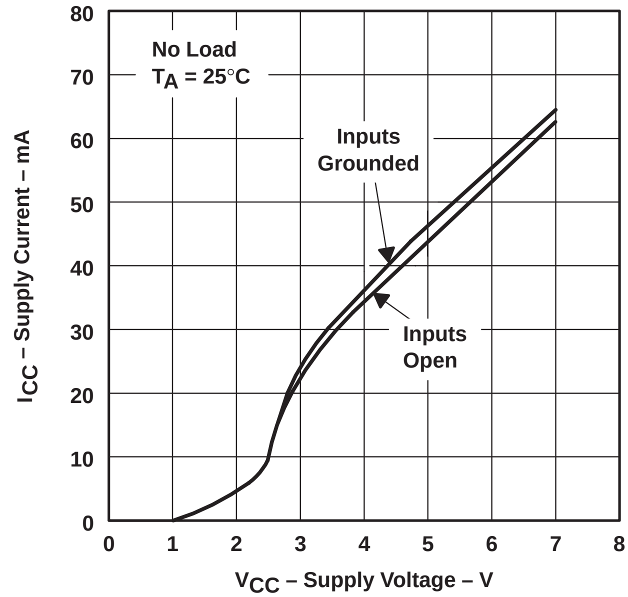


Figure 10

SUPPLY CURRENT
(BOTH DRIVERS)
vs
FREE-AIR TEMPERATURE

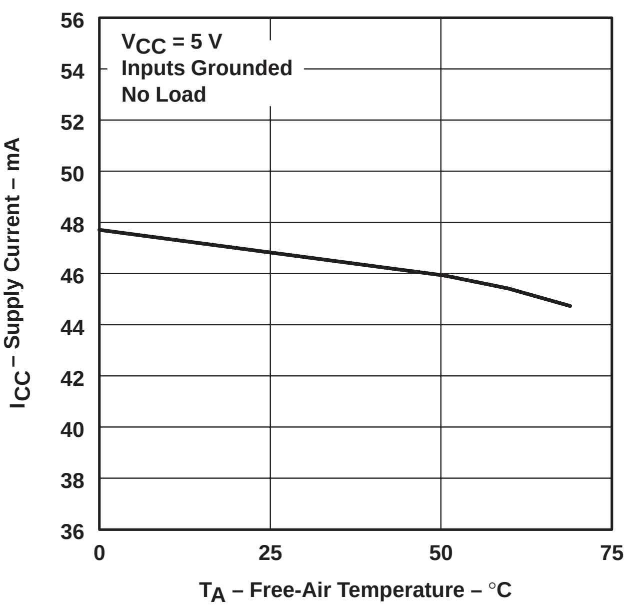


Figure 11

SUPPLY CURRENT
(BOTH DRIVERS)
vs
FREQUENCY

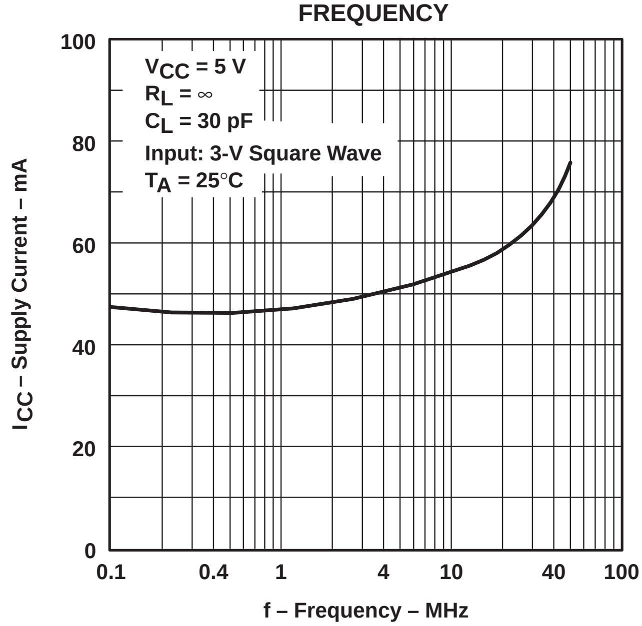


Figure 12

TYPICAL CHARACTERISTICS

PROPAGATION DELAY TIME FROM DATA INPUTS vs FREE-AIR TEMPERATURE

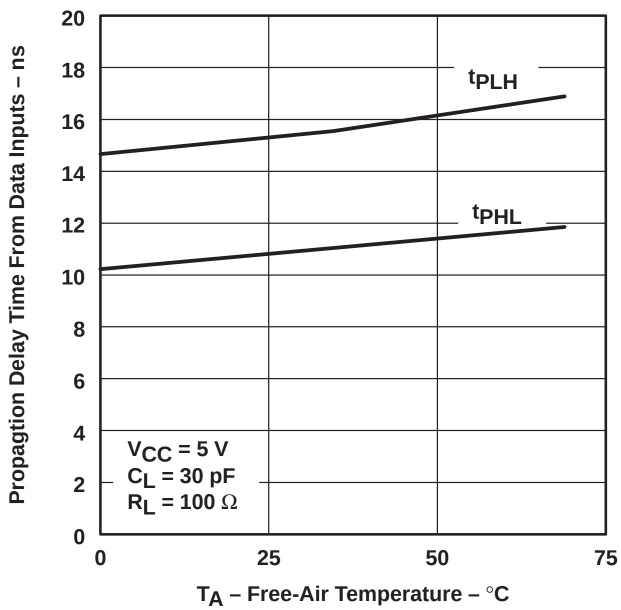


Figure 13

OUTPUT ENABLE AND DISABLE TIME vs FREE-AIR TEMPERATURE

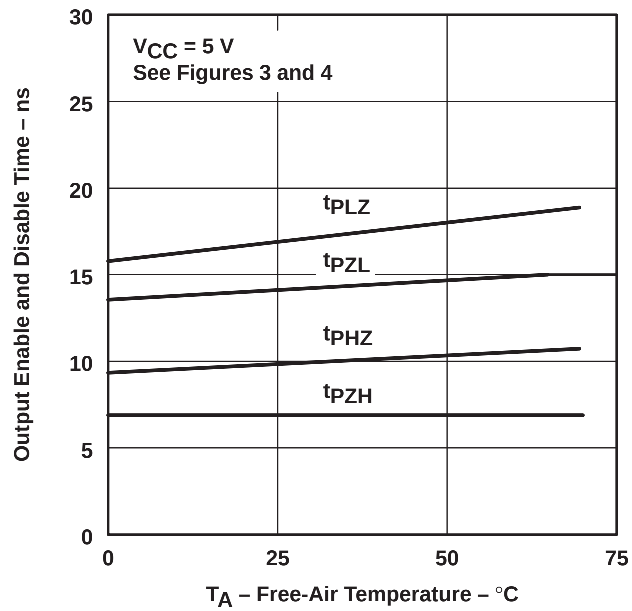


Figure 14

IMPORTANT NOTICE

Texas Instruments and its subsidiaries (TI) reserve the right to make changes to their products or to discontinue any product or service without notice, and advise customers to obtain the latest version of relevant information to verify, before placing orders, that information being relied on is current and complete. All products are sold subject to the terms and conditions of sale supplied at the time of order acknowledgement, including those pertaining to warranty, patent infringement, and limitation of liability.

TI warrants performance of its semiconductor products to the specifications applicable at the time of sale in accordance with TI's standard warranty. Testing and other quality control techniques are utilized to the extent TI deems necessary to support this warranty. Specific testing of all parameters of each device is not necessarily performed, except those mandated by government requirements.

CERTAIN APPLICATIONS USING SEMICONDUCTOR PRODUCTS MAY INVOLVE POTENTIAL RISKS OF DEATH, PERSONAL INJURY, OR SEVERE PROPERTY OR ENVIRONMENTAL DAMAGE ("CRITICAL APPLICATIONS"). TI SEMICONDUCTOR PRODUCTS ARE NOT DESIGNED, AUTHORIZED, OR WARRANTED TO BE SUITABLE FOR USE IN LIFE-SUPPORT DEVICES OR SYSTEMS OR OTHER CRITICAL APPLICATIONS. INCLUSION OF TI PRODUCTS IN SUCH APPLICATIONS IS UNDERSTOOD TO BE FULLY AT THE CUSTOMER'S RISK.

In order to minimize risks associated with the customer's applications, adequate design and operating safeguards must be provided by the customer to minimize inherent or procedural hazards.

TI assumes no liability for applications assistance or customer product design. TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right of TI covering or relating to any combination, machine, or process in which such semiconductor products or services might be or are used. TI's publication of information regarding any third party's products or services does not constitute TI's approval, warranty or endorsement thereof.